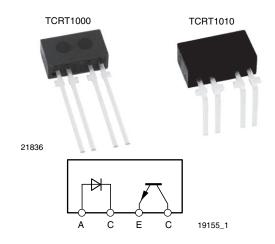


Vishay Semiconductors

# **Reflective Optical Sensor With Transistor Output**

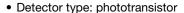


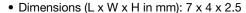
#### **DESCRIPTION**

The TCRT1000 and TCRT1010 are reflective sensors which include an infrared emitter and phototransistor in a leaded package which blocks visible light.

#### **FEATURES**

· Package type: leaded





• Peak operating distance: 1 mm

 Operating range within > 20 % relative collector current: 0.2 mm to 4 mm

Typical output current under test: I<sub>C</sub> = 0.7 mA

Daylight blocking filter

• Emitter wavelength: 950 nm

• Lead (Pb)-free soldering released

 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

 Optoelectronic scanning and switching devices i.e., index sensing, coded disk scanning etc. (optoelectronic encoder assemblies for transmissive sensing).

PRODUCT SUMMARY				
PART NUMBER	DISTANCE FOR MAXIMUM CTR <sub>REL</sub> (1) (mm)	DISTANCE RANGE FOR RELATIVE I <sub>out</sub> > 20 % (mm)	TYPICAL OUTPUT CURRENT UNDER TEST (2) (mA)	DAYLIGHT BLOCKING FILTER INTEGRATED
TCRT1000	1	0.2 to 4	0.7	Yes
TCRT1010	1	0.2 to 4	0.7	Yes

#### Notes

(1) CTR: current transfere ratio, I<sub>out</sub>/I<sub>in</sub>

(2) Conditions like in table basic charactristics/sensor

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	VOLUME (1)	REMARKS		
TCRT1000	Bulk	MOQ: 1000 pcs, 1000 pcs/bulk	Straight leads		
TCRT1010	Bulk	MOQ: 1000 pcs, 1000 pcs/bulk	Bent leads		

#### Note

(1) MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
SENSOR					
Total power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>tot</sub>	270	mW	
Ambient temperature range		T <sub>amb</sub>	-40 to +85	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C	
Soldering temperature	2 mm distance to package, t ≤ 5 s	T <sub>sd</sub>	260	°C	
INPUT (EMITTER)					
Reverse voltage		$V_{R}$	5	V	
Forward current		I <sub>F</sub>	100	mA	
Forward surge current	t <sub>p</sub> ≤ 100 μs	I <sub>FSM</sub>	1.5	A	
Power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>V</sub>	170	mW	
Junction temperature		Tj	100	°C	



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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
OUTPUT (DETECTOR)						
Collector emitter voltage		V <sub>CEO</sub>	32	V		
Emitter collector voltage		V <sub>ECO</sub>	5	V		
Collector current		I <sub>C</sub>	50	mA		
Power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>V</sub>	100	mW		
Junction temperature		T <sub>j</sub>	100	°C		

### **ABSOLUTE MAXIMUM RATINGS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

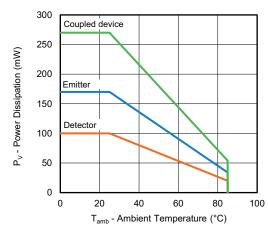


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
SENSOR						
Collector current	$V_{CE} = 5 \text{ V}, I_F = 20 \text{ mA},$ d = 1 mm (Fig. 2)	I <sub>C</sub> <sup>(1)</sup>	0.6	0.7	-	mA
Cross talk current	$V_{CE} = 5 \text{ V}, I_F = 20 \text{ mA}$	I <sub>CX</sub> (2)	-	-	1	μΑ
Collector emitter saturation voltage	$I_F = 20 \text{ mA}, I_C = 0.1 \text{ mA},$ d = 1 mm (Fig. 2)	V <sub>CEsat</sub> (1)	-	-	0.3	V
INPUT (EMITTER)	INPUT (EMITTER)					
Forward voltage	I <sub>F</sub> = 100 mA	V <sub>F</sub>	-	1.6	1.7	V
Peak wavelength	I <sub>F</sub> = 100 mA	λ <sub>P</sub>	950	-	-	nm
OUTPUT (DETECTOR)						
Collector emitter voltage	I <sub>C</sub> = 1 mA	$V_{CEO}$	32	-	-	V
Emitter collector voltage	I <sub>E</sub> = 100 μA	V <sub>ECO</sub>	5	-	-	V
Collector dark current	$V_{CE} = 10 \text{ V}, I_F = 0 \text{ A}, E = 0 \text{ Ix}$	I <sub>CEO</sub>	=	-	200	nA

#### Notes

 $<sup>^{(1)}</sup>$  Measured with the "Kodak neutral test card", white side with 90 % diffuse reflectance

<sup>(2)</sup> Measured without reflecting medium



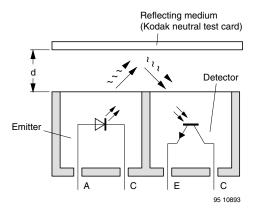


Fig. 2 - Test Condition

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

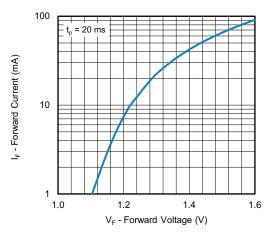


Fig. 3 - Forward Current vs. Forward Voltage

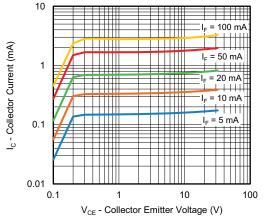


Fig. 5 - Collector Current vs. Collector Emitter Voltage

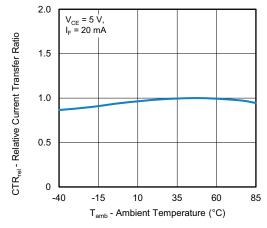


Fig. 4 - Relative Current Transfer Ratio vs. Ambient Temperature

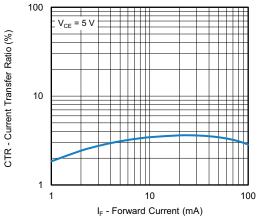


Fig. 6 - Current Transfer Ratio vs. Forward Current



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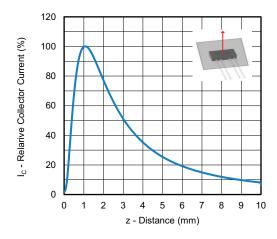


Fig. 7 - Collector Current vs. Distance

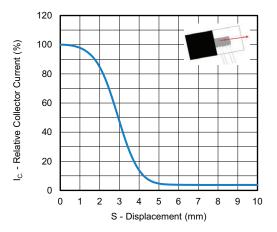
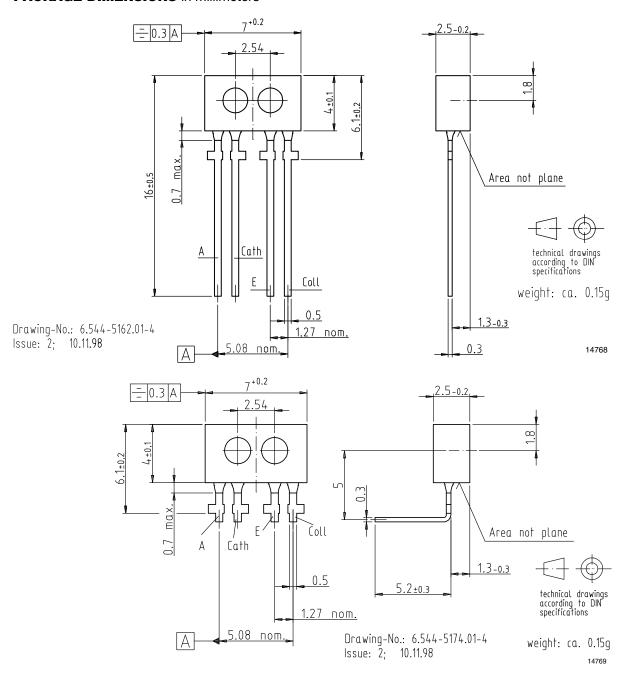


Fig. 8 - Relative Collector Current vs. Displacement



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#### **PACKAGE DIMENSIONS** in millimeters





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